

DATE: Monday, October 18, 2004

## WEST Search History

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DB=PGPB, USPT, USOC, EPAB, JPAB, DWPI, TDBD; PLUR=YES; OP=ADJ				
<b>1</b>	L8	12 and 16	12	
m	L7	11 and L6	5	
	L6	deep junction	880	
177	L5	11 and I.4	1	
$\blacksquare$	I.Ą	(spaced or spaced apart) near3 ((insulator or insulating) bodies)	369	
n	L3	11 and 12	1	
	L2	((insulator or insulation or insulating or dielectric or oxide) (layer or film)) same (second thickness)	1331	
1	L1	MOSgated or MOS gated or metal oxide semiconductor gated or metal oxide silicon gated	720	

END OF SEARCH HISTORY

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## ePHOENIX Reference Manager

	 550000000000000000000000000000000000000
<b>Application Number:</b>	Submit
Application number.	 ······································

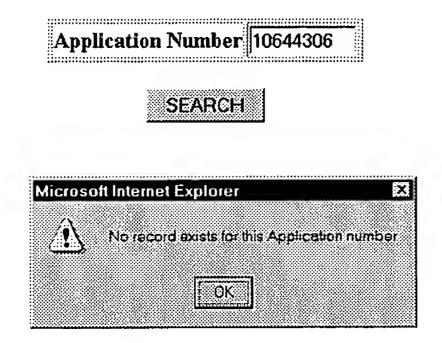
No Forms Found for Application Number 10/644,306

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## **Electronic Information Disclosure Statement**

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